Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-594-7940

| Inclosure Material: |
|--|
| Glass |
| Overall Length: |
| Between 0.130 inches and 0.146 inches |
| Electrode Internally-electrically Connected To Case: |
| Cathode |
| Terminal Circle Diameter: |
| Between 0.063 inches and 0.067 inches |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Current Rating Per Characteristic: |
| 650.0 milliamperes forward current, peak total value |
| Maximum Operating Tempurature Per Measurement Point: |
| 175.0 degrees celsius ambient air |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |
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